



HAL
open science

Stability of Optoelectronic Materials and Devices: a Themed Collection

Zhuoying Chen, Dinesh Kabra, Yana Vaynzof

► **To cite this version:**

Zhuoying Chen, Dinesh Kabra, Yana Vaynzof. Stability of Optoelectronic Materials and Devices: a Themed Collection. Journal of Materials Chemistry C, 2023, 11 (5), pp.1608-1609. 10.1039/D3TC90009F . hal-04287785

HAL Id: hal-04287785

<https://hal.sorbonne-universite.fr/hal-04287785>

Submitted on 20 Nov 2023

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

Stability of Optoelectronic Materials and Devices: a Themed Collection

Zhuoying Chen,^a Dinesh Kabra, and Yana Vaynzof

^a LPEM, ESPCI Paris, PSL Research University, Sorbonne Université, CNRS, 10 Rue Vauquelin, F- 75005 Paris, France. E-mail: zhuoying.chen@espci.fr

^b Department of Physics, Indian Institute of Technology Bombay, Powai, Mumbai-400076, India. E-mail: dkabra@iitb.ac.in

^c Dresden Integrated Center for Applied Physics and Photonic Materials (IAPP) and Center for Advancing Electronics Dresden (cfaed), Technische Universität Dresden, Dresden 01062, Germany. E-mail: yana.vaynzof@tu-dresden.de

Recent years have seen enormous strides made in the development of novel materials for optoelectronic devices. Particularly noteworthy examples are non-fullerene acceptors for organic photovoltaics,¹ 2D materials for photodetectors² and metal halide perovskites for a broad range of devices, such as light-emitting diodes or solar cells.³ With remarkable advances in their synthesis, processing and integration into functional devices, the performance of these optoelectronic devices is reaching competitive levels. This makes the future of such novel materials and their application in optoelectronics on an industrial scale more promising than ever. However, to realise their full potential on a commercial level, not only the desired function and performance need to be achieved, but also their stability needs to be enhanced in order to reach the necessary lifetimes set by the different applications.

The study of material and device stability naturally takes a secondary role in the development of novel materials. Researchers focus on showcasing the desired performance first, in order to provide proof-of-concept devices and trigger further developments. Nowadays, several classes of materials have already reached a certain level of maturity and the demonstration of superior performance is no longer the only goal of research. More and more attention is now diverted to understanding the fundamental processes that govern material and device degradation and the development of suitable mitigation strategies.⁴⁻⁵ The themed collection “Stability of Optoelectronic Materials and Devices” aims to highlight some of the best reports dedicated to the topic and motivate further research into this challenging and exciting field of materials chemistry.

From a chemical point of view, understanding how the molecular structure of a molecule impacts on its stability is highly important. This is highlighted in the excellent report by K. J. Thorley *et al.*, who investigated a series of different derivatives of anthradithiophenes to identify the factors that influence their photostability (<https://doi.org/10.1039/D2TC02922G>). The authors demonstrate that substituents at certain molecular positions tend to increase photostability, with the optimal position depending on the type of substituent. Based on these insights the authors suggest a range of future design principles that can lead either to more stable materials for optoelectronics, or alternatively more reactive for applications as sensors.

The processing of materials during device fabrication may also impact on the stability of the optoelectronic device. The work by C. Zhao *et al.* illustrates this by comparing standard spin-coating of a binary polymer blend to a sequential deposition of the same polymers during the fabrication of an organic solar cell

(<https://doi.org/10.1039/D2TC04142A>). The researchers demonstrate that sequential processing not only results in improved photovoltaic performance, but also enhanced device stability. These improvements are associated with the differences in the vertical distribution of the two polymers achieved by the different processing methods.

An alternative approach to increasing device stability is through the engineering of its structure to introduce additional components that mitigate the deterioration of performance by suppressing the degradation pathway. This approach was adopted by S. Yoon *et al.* who introduced various CeO_{2-x} nanostructures into an organic solar cell structure to act as free radical scavengers (<https://doi.org/10.1039/D2TC04152A>). The authors demonstrated that single-crystalline hollow CeO_{2-x} nanorods were very effective as hydroxyl radical scavengers, resulting in an enhanced device stability of the solar cell upon continuous illumination.

These selected examples illustrate the broad range of research fields that are involved in the complicated task of improving the stability of optoelectronic materials and devices. These range from chemistry to materials science to device physics and engineering and include a plethora of challenging research questions. We hope that this themed collection inspires the readers to extend their own research to include the study of material and device degradation and the development of approaches for their enhancement.

Guest Editors:

Dr Zhuoying Chen is a CNRS researcher (Chargé de recherche) working in the Laboratoire de Physique et d'Etude des Matériaux (LPEM, CNRS-UMR 8213) at ESPCI Paris, a unit of PSL (Paris Sciences et Lettres) University in France. She has been a Marie-Curie fellow. She is the project leader of an ANR (Agence Nationale de



la Recherche) young researcher project (ANR-2011-JS09-004-01-PvCoNano) and the French-side leader of an ANR international France–Germany collaborative project (ANR-17-CE05-0028-01). Her current research focuses on the optoelectronic application (in terms of solar cells and photodetectors) of colloidal and organic–inorganic hybrid nanomaterials synthesized and engineered by bottom-up approaches.

Prof. Dinesh Kabra is working at the Department of Physics at IIT Bombay, Mumbai – India. He is in charge of emerging PV technologies at the National Center for Photovoltaic Research and Education (NCPRE) at IITB and is also an associated faculty member at the Center for Semiconductors for Innovations and Technologies (SEMIX). Prof. Kabra is the recipient of the DST Solar



Challenge Award 2022, Early Research Achiever Award 2015 and Best Paper Award 2016 of the Industrial Research and Consultancy Center, IIT Bombay. His current research interest involves solution-processible inorganic and organic

semiconductors, the understanding of their charge transport and photo-physics and transfer of that knowledge to the design of high performance optoelectronic and piezotronic devices.

Prof. Dr Yana Vaynzof is the Chair for Emerging Electronic Technologies at the Technical University of Dresden (Germany) and the Director of the Institute for Emerging Electronic Technologies at the Leibniz Institute for Solid State and Materials Research Dresden (IFW). Yana Vaynzof is the recipient of a number of fellowships and awards, including the ERC Starting Grant, Gordon Wu



Fellowship, Henry Kressel Fellowship, Fulbright-Cottrell Award and the Walter Kalkhof-Rose Memorial Prize. Her research interests lie in the field of emerging photovoltaics focusing on the study of material and device physics of organic, quantum dot and perovskite solar cells by integrating device fabrication and characterisation with the application and development of advanced spectroscopic methods.

References:

-
- [1] J. Mater. Chem. A 2022,10, 3255-3295
 - [2] <https://doi.org/10.3389/fchem.2022.905404>
 - [3] APL Materials 2021, 9, 109202.
 - [4] Nature Energy 2020, 5, 947–949
 - [5] Nature Communications 2022, 13, 7639